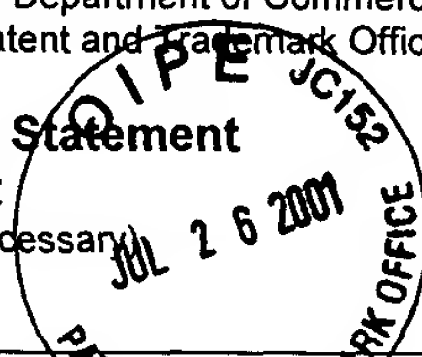


Substitute Form PTO-1449 (Modified) U.S. Department of Commerce Patent and Trademark Office Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR 1.98(b))	Attorney's Docket No. 12732-007001	Application No. 09/768,618
	Applicant Setsuo NAKAJIMA et al.	
	Filing Date January 25, 2001	Group Art Unit Unknown

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U.S. Patent Documents							
Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
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Examiner Signature <i>Stanetta Lopez</i>	Date Considered 8/14/02
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

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		Applicant Setsuo NAKAJIMA et al.	
		Filing Date January 25, 2001	Group Art Unit Unknown

U.S. Patent Documents							
Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
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Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AII							

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
SDI	AJJ	Bonnel et al., "Polycrystalline Silicon Thin-Film Transistors with Two-Step Annealing Process," <u>IEEE Electron Device Letters</u> , 1993, 14(12):551-553
SDI	AKK	Fujieda et al., "Self-referenced Poly-Si TFT Amplifier Readout for a Linear Image Sensor," <u>IEEE</u> , 1993, pp. 587-590
SDI	ALL	Fuse et al., "Performance of Poly-Si Thin Film Transistors Fabricated by Excimer-Laser Annealing of SiH ₄ - and Si ₂ H ₆ - Source Low Pressure Vapor Deposited a-Si Films with or without Solid-Phase Crystallization," <u>Solid State Phenomena</u> , 1994, Vols. 37-38, pp. 565-570

Examiner Signature <i>Stanetta base</i>	Date Considered 8/14/02
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